

FCC ID: A3LSMS926U

Power Density Simulation Report

Revision A

October 18, 2023

SAMSUNG ELECTRONICS

1. Simulation methodology for Power Density (PD)

1.1 Simulation tool

1.1.1 Tool description

For the simulation approach to calculating power density (PD) evaluation for mobile phone with mmWave antenna modules, ANSYS Electromagnetics suite version 2023.R2 (HFSS) is used. ANSYS HFSS is one of several commercial tools for 3D full-wave electromagnetic simulation used for antenna and RF structure design of high frequency component. ANSYS Electromagnetics suite version 2023.R2 (HFSS) is implemented based on Finite Element Method (FEM), which operates in the frequency domain.

1.1.2 Mesh and Convergence criteria

To solve the PD analysis using FEM, volume area containing simulated objects should be subdivided into electrically small parts that are called finite elements as the unknown functions. To subdivide system, the adaptive mesh technique in ANSYS Electromagnetics suite version 2023.R2 (HFSS) is used. ANSYS Electromagnetics suite version 2023.R2 (HFSS) starts to refine the initial mesh based on wavelength and calculate the error to iterative process for adaptive mesh refinement. The determination parameter of the number of iteration in ANSYS Electromagnetics suite version 2023.R2 (HFSS) is defined as convergence criteria, delta S, and the iterative adaptive mesh process repeats until the delta S is met. In ANSYS Electromagnetics suite version 2023.R2 (HFSS), the accuracy of converged results depends on the delta S. Figure 1 is an example of adaptive mesh of the device (cross-section of top view).

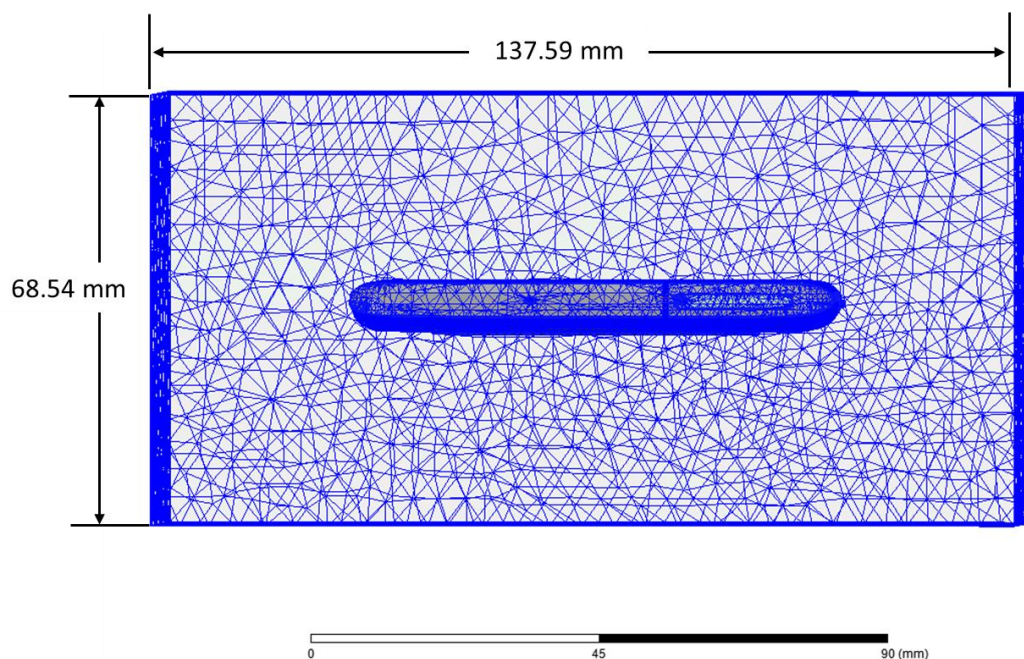


Figure 1 Example of the adaptive mesh technique (Top view)

1.1.3 Power density calculation

After solving 3D full-wave electromagnetic simulation, various kinds of physical quantities can be obtained. To calculate PD evaluation, two physical quantities, an electric field (\vec{E}) and a magnetic field (\vec{H}) are needed. The actual consumption power can be expressed as the real term of the Poynting vector (\vec{S}) from the cross product of \vec{E} and complex conjugation of \vec{H} as shown below:

$$\langle \vec{S} \rangle = \text{Re} \left(\frac{1}{2} \vec{E} \times \vec{H}^* \right)$$

$\langle \vec{S} \rangle$ can be expressed as point power density based on a peak value of each spatial point on mesh grids, and obtained directly from ANSYS Electromagnetics suite version 2023.R2 (HFSS).

From the point power density $\langle \vec{S} \rangle$, the spatial-averaged power density (PD_{av}) on an evaluated area (A) can be derived as shown below:

$$PD_{av} = \frac{1}{A} \int_A \langle \vec{S} \rangle \cdot d\vec{s} = \frac{1}{2A_{av}} \iint_{A_{av}} \| \text{Re}\{E \times H^*\} \| dA$$

, where the spatial-averaged power density (PD_{av}) is total power density value considering on x, y and z components of point power density $\langle \vec{S} \rangle$ and the evaluated area (A) is 4cm^2 .

1.2 Simulation setup

1.2.1 3D modeling

Figure 2 shows the simulation model which is mounted two mmWave antenna modules. The simulation modeling includes most of the entire structure of device itself such as PCB, metal frame, battery, cables, and legacy antennas as well as mmWave antenna modules called as Ant M and Ant N. The modeling contains the entire EUT to enable a Smart transmit GEN2, as well. Ant M is placed on the left side and antennas are facing the back side, and Ant N is placed on the right side and antennas are facing the right side of the device.

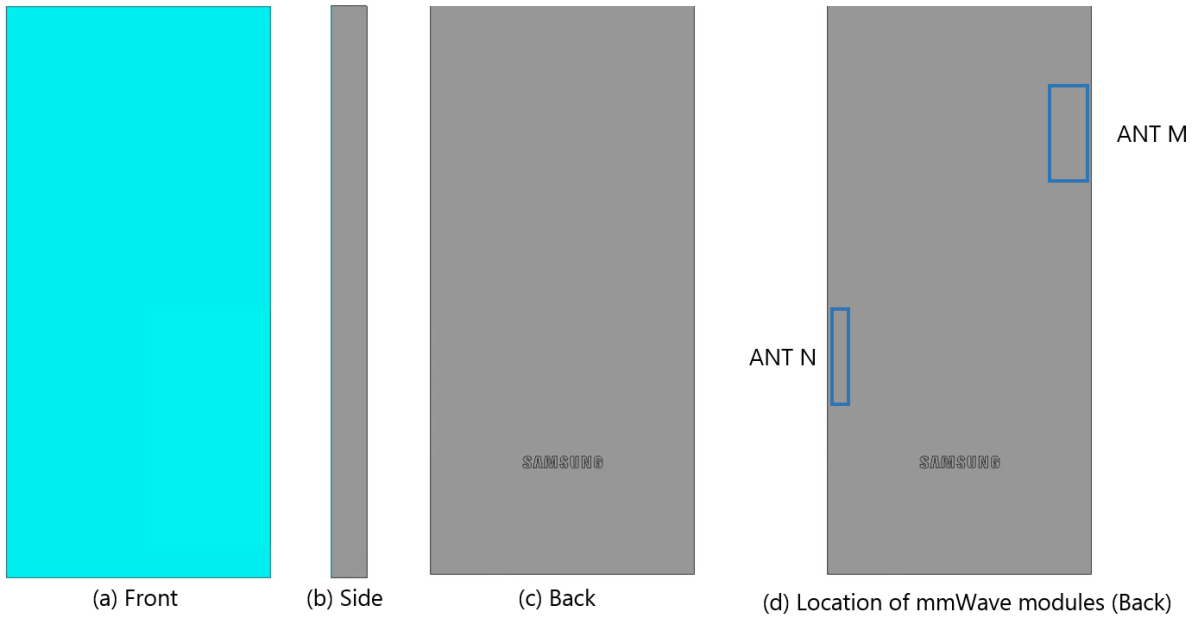


Figure 2 Simulation model which is mounted two mmWave antenna modules

1.2.2 PD evaluation planes

Table 1 shows the PD evaluation planes for each mmWave antenna module and Figure 3 shows the PD evaluation planes and truncation area of the simulation model to find worst case of beamforming cases.

Please note that the “right” and “left” edge of mentioned in this report are defined from the perspective of looking at the device from the front side.

Table 1. PD evaluation planes

| Module | Front | Back | Left From Front View | Right From Front View | Top | Bottom |
|--------|-------|------|----------------------|-----------------------|-----|--------|
| | S1 | S2 | S3 | S4 | S5 | S6 |
| Ant M | O | O | O | O | O | O |
| Ant N | O | O | O | O | O | O |

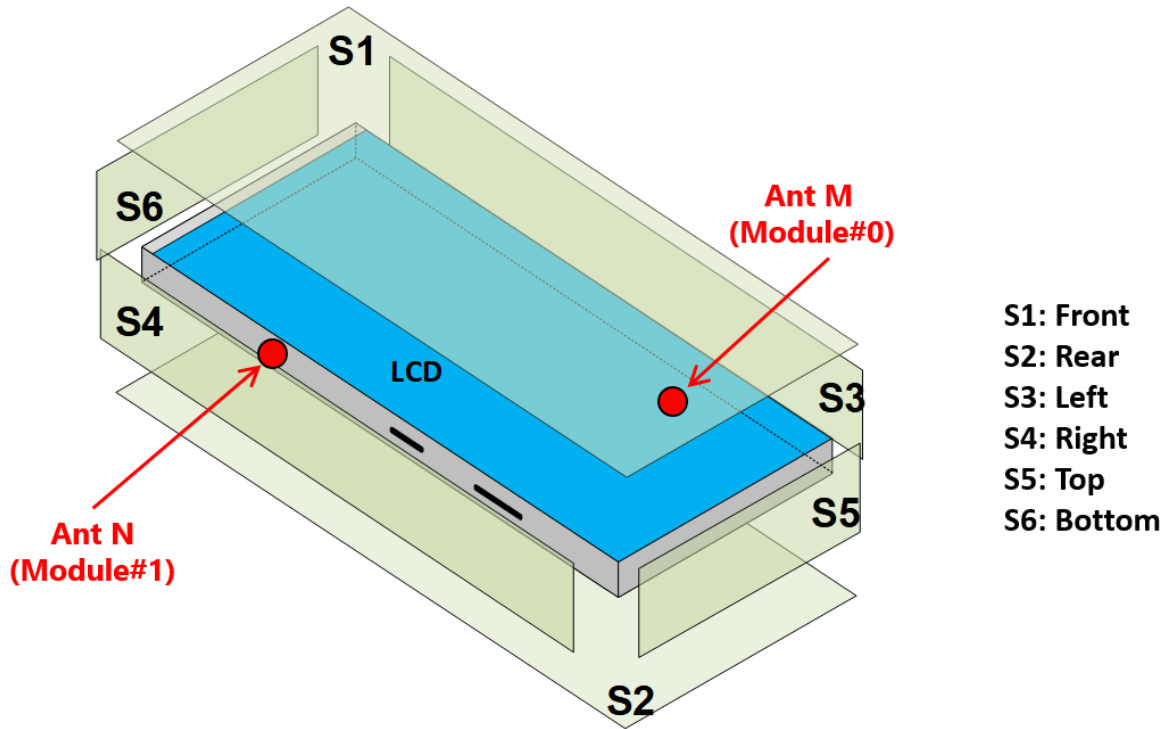


Figure 3. PD evaluation planes

1.2.3 Boundary condition

To simulate electromagnetic tool based on FEM, the boundary condition allows electromagnetic waves to be electrically open at the boundary and radiated far away without reflection. ANSYS Electromagnetics suite version 2023.R2 (HFSS) can support the absorbing boundary condition (ABC) for radiation boundary and make normally a quarter wave length from the radiating structure. In this report, to cover all beamforming cases of mmWave antenna modules, 40 mm spacing from the device for each surfaces were adopted. This distance is sufficiently large enough for “Qualcomm Input Power Limit Generator” to extract valid E- and H-fields from all adjacent exposure surfaces of the EUT.

1.2.4 Source excitation condition

The number of antenna ports of ANT M and ANT N for source excitation are the same. The antenna port of ANT M and N is divided into 10 ports for n261 and n258 1 x 5 patch array antennas, 10 ports for n260 1 x 5 patch array antennas. In the 10 ports included in each patch antenna, 5 ports are divided into vertical polarization feeding, and the other 5 ports are divided into horizontal polarization feeding.

Figure 4 shows the ANT M module structure and surrounding structure. The ANT M module is encrypted in the ANSYS Electromagnetics suite (HFSS) and can only check the feeding position.

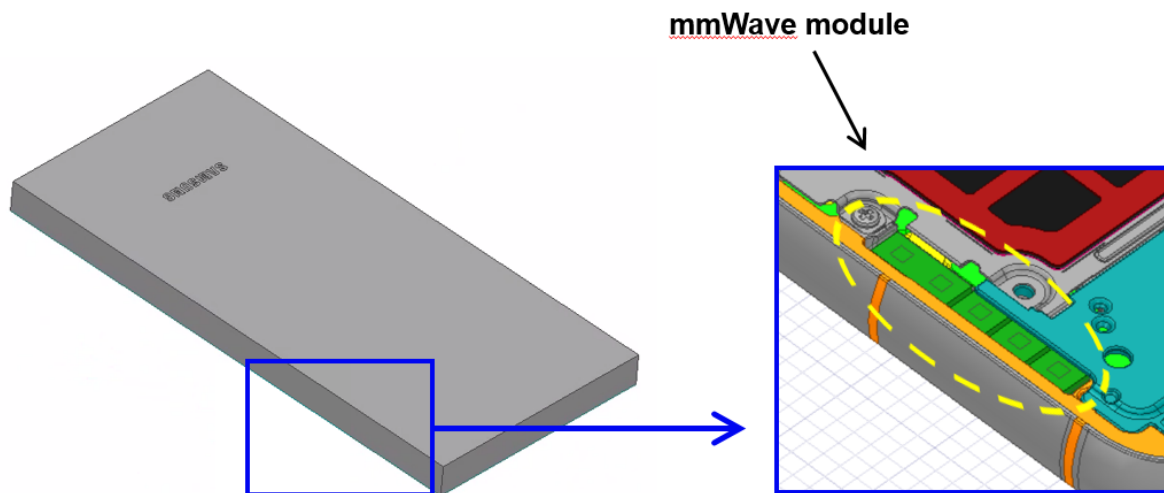


Figure 4. mmWave module (ANT M)

After finishing 3D full wave electromagnetic simulation of modeling structure, the magnitude and phase information can be loaded for each port by using “Edit Sources” function in ANSYS Electromagnetics suite (HFSS). Figure 5 shows an example of antenna port excitations.

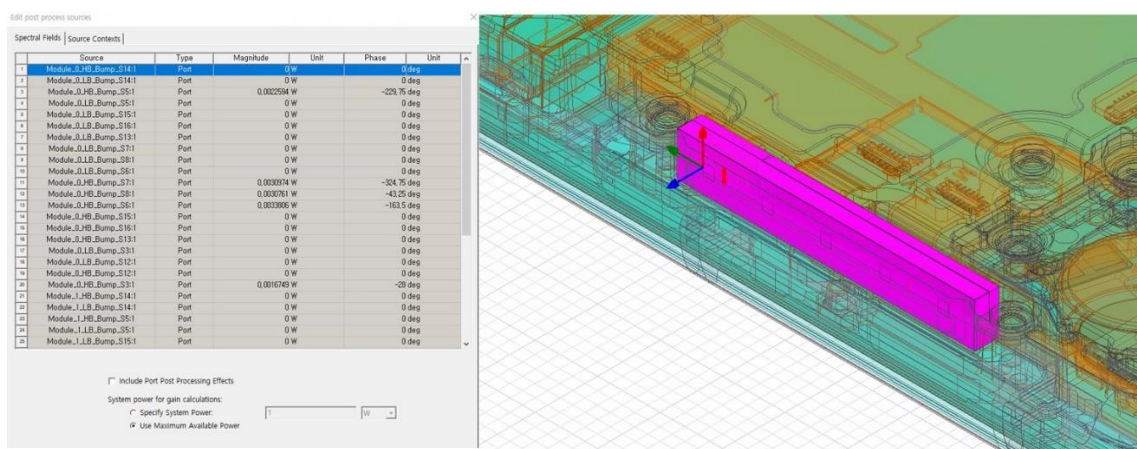


Figure 5. An example of port excitation (ANT N)

Since ANSYS Electromagnetics suite (HFSS) uses FEM solver based on frequency domain analysis method, the input source for the port excitation applies sinusoidal waveform for each frequency.

1.2.5 Condition of simulation completion

The simulation completion condition of ANSYS Electromagnetics suite (HFSS) is defined as delta S. The ANSYS Electromagnetics suite (HFSS) calculates the S-parameter for the mesh conditions of each step and determines whether to proceed with the operation of the next step by comparing the difference

between the S-parameters in the previous step. A difference between the previous step and the current step of S-parameter is expressed as delta S, and the delta S generally sets 0.02. The simulation result of this report is the result of setting delta S to 0.02.

2. Simulation verification

2.1 Spatial-averaged power density and `sim.powerlimit`

As mentioned in the previous chapter, the Poynting vector (\vec{S}) can be obtained through cross product of an electric field (\vec{E}) and complex conjugate of a magnetic field (\vec{H}). The real term of the Poynting vector can be described as the point power density or peak power density. Using the point power density, the spatial-averaged power density can be obtained by the integral of 4 cm^2 at 2.5 mm intervals of the point power density result. Figure 6 shows examples of the distribution plot of point power density and the averaged power density.

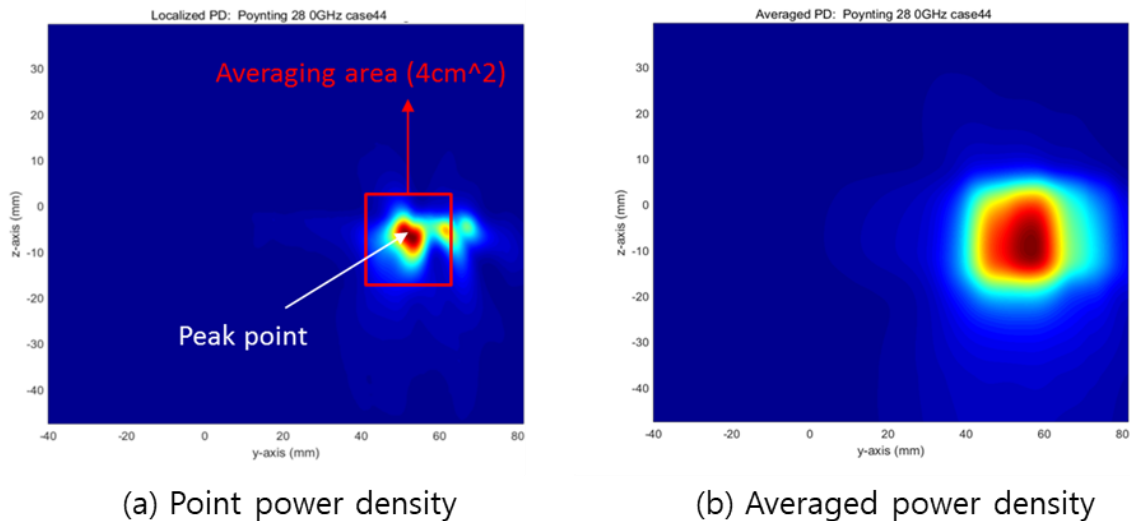


Figure 6. Power density distribution (Example)

For the Smart transmit GEN2, the “Qualcomm Input Power Limit Generator” were used to extract E- and H-fields from the validated simulation and to assess the mutual coupling between all the mmWave antenna modules and all the beams in the codebook to determine the backoff value for each mmWave module. Note the assessment and backoff value derivation are automated with “Qualcomm Input Power Limit Generator”. Once the script is done with assessment, it will provide the `sim.powerlimit` (backoff is already included) for all the beams for all three channels for the specified `PDdesigntarget`. This mode take the minimum `sim.powerlimit` out of all three channels (low, mid and high) and use the resulted `sim.powerlimit`.

2.2 Comparison between simulation, measurement

In this section, the simulated-power density distributions and measured-power density distributions are compared to each mmWave antenna. Furthermore, to verify the Smart transmit GEN2, the PD distributions printing out from the “Qualcomm Input Power Limit Generator” are added.

Based on comparison of power density distributions, the power densities of simulated, measured and the “Qualcomm Input Power Limit Generator” have a good correlation. The discrepancy in amplitude between the “Qualcomm Input Power Limit Generator” 4cm² averaged power density and measured 4cm² averaged power density is considered as housing influence and used in determining input power limit for each beam for RF exposure compliance.

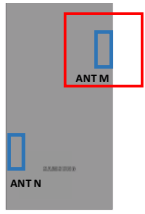
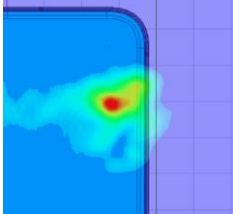
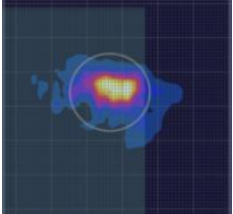
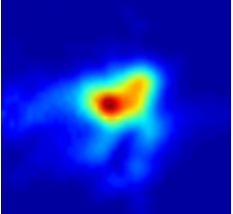
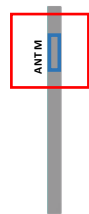
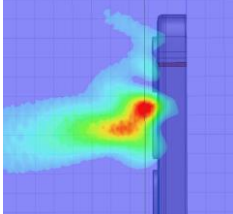
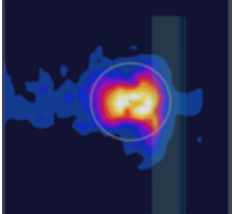
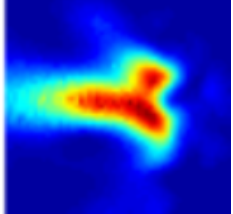
The input powers per each active port are listed below for both Simulation and Measurement validation and power density characterization. For Simulation, these values were entered directly into HFSS model. For measurement, FTM S/W was used to input these values for each active port also.

| Mode/Band | Antenna | Input Power (dBm) | |
|------------|---------|-------------------|------|
| | | SISO | MIMO |
| 5G NR n261 | M Patch | 6.0 | 6.0 |
| | N Patch | 6.0 | 6.0 |
| 5G NR n260 | M Patch | 6.0 | 6.0 |
| | N Patch | 6.0 | 6.0 |
| 5G NR n258 | M Patch | 6.0 | 6.0 |
| | N Patch | 6.0 | 6.0 |

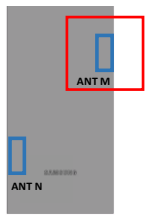
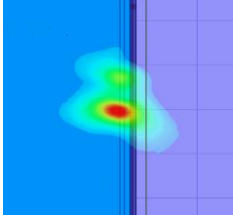
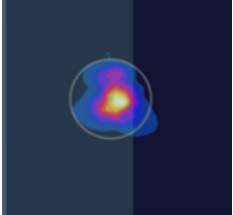
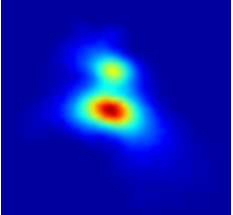
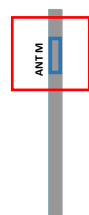
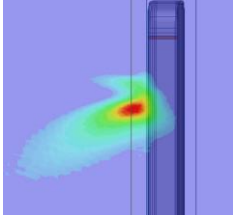
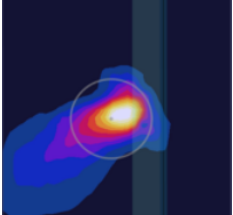
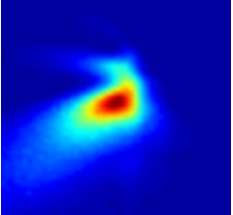
* The below simulation and measurement result were performed at 2mm evaluation distance and 28GHz / 38.5GHz / 24.8 GHz. The *input.power.limit* was determined based on below results.

| Band | Channel | Module | Type(P or D) | Side | Beam ID | PLS (10 dBm) | Sim. PD (mW/cm ²) | Meas. PD (mW/cm ²) * Circle Avg |
|-------|--------------------------------|--------|--------------|-------|---------|--------------|-------------------------------|---|
| n261 | Mid Ch. 2077891 (27923.5 MHz) | M | Patch | Rear | 35 | 60 | 1.480 | 0.775 |
| | | | | Left | | | 0.530 | 0.272 |
| | | | | Rear | 293 | | 2.090 | 1.39 |
| | | | | Left | | | 1.180 | 0.724 |
| | | N | Patch | Rear | 30 | | 0.880 | 0.309 |
| | | | | Right | | | 1.640 | 0.73 |
| | | | | Rear | 289 | | 0.780 | 0.344 |
| | | | | Right | | | 1.420 | 1.06 |
| n260 | Mid Ch. 2253331 (38449.9 MHz) | M | Patch | Rear | 28 | 60 | 1.309 | 0.487 |
| | | | | Left | | | 0.737 | 0.321 |
| | | | | Rear | 291 | | 1.254 | 0.735 |
| | | | | Left | | | 0.598 | 0.314 |
| | | N | Patch | Right | 33 | | 2.253 | 0.989 |
| | | | | Front | | | 0.823 | 0.548 |
| | | | | Right | 286 | | 1.835 | 1.02 |
| | | | | Front | | | 1.339 | 0.387 |
| n258 | Mid Ch. 2025833 (24800.04 MHz) | M | Patch | Rear | 35 | 60 | 1.199 | 0.734 |
| | | | | Left | | | 0.526 | 0.197 |
| | | | | Rear | 284 | | 2.152 | 1.41 |
| | | | | Left | | | 1.066 | 0.602 |
| | | N | Patch | Rear | 40 | | 1.329 | 0.618 |
| | | | | Right | | | 1.838 | 0.814 |
| | | | | Rear | 288 | | 0.505 | 0.313 |
| | | | | Right | | | 0.889 | 0.692 |
| Front | 286 | 0.446 | 0.287 | | | | | |

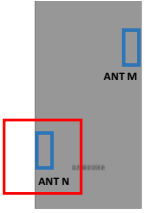
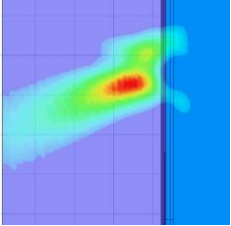
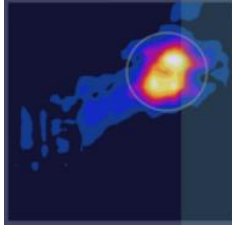
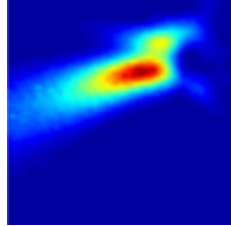
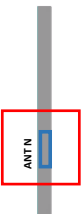
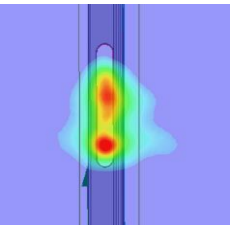
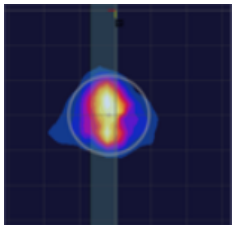
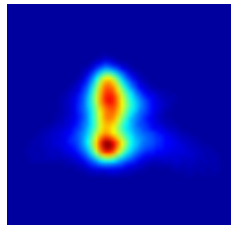
Table 2-1, n261 ANT M-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|-----------|---|---|--|---|
| 35 | S2 (Rear) |  |  |  |  |
| | S3 (Left) |  |  |  |  |

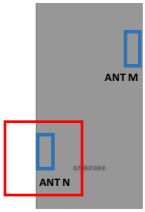
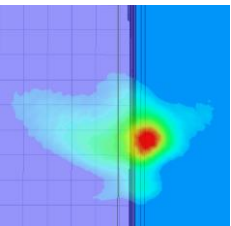
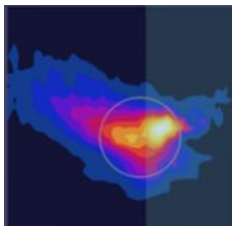
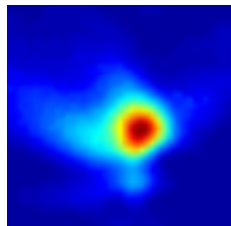
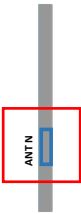
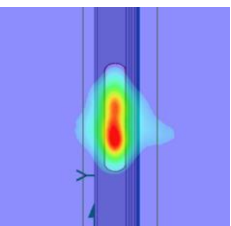
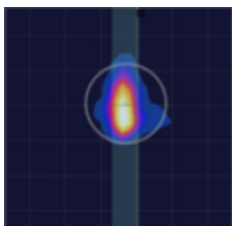
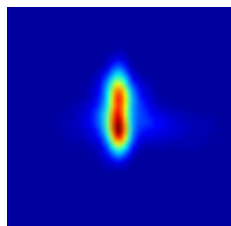
● Table 2-2, n261 ANT M-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|-----------|---|---|--|---|
| 293 | S2 (Rear) |  |  |  |  |
| | S3 (Left) |  |  |  |  |

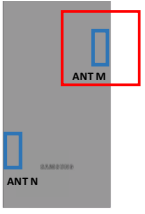
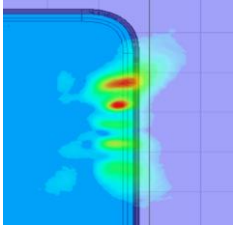
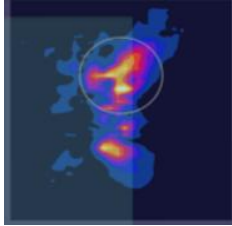
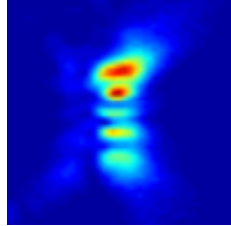
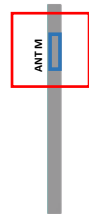
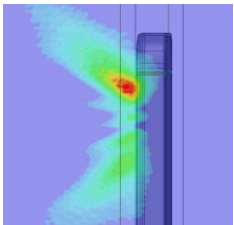
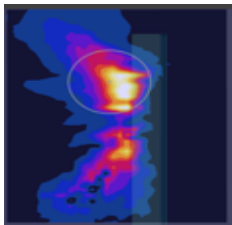
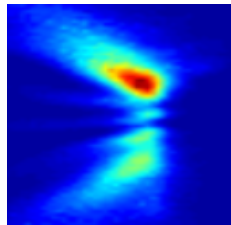
● Table 2-3, n261 ANT N-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|------------|---|---|--|---|
| 30 | S2 (Rear) |  |  |  |  |
| | S4 (Right) |  |  |  |  |

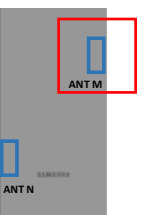
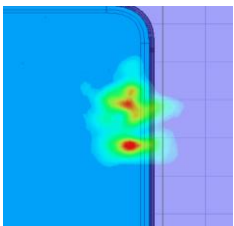
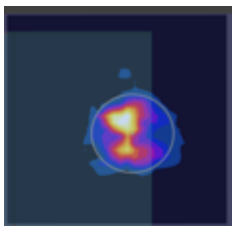
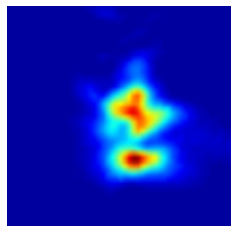
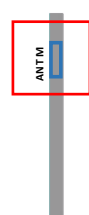
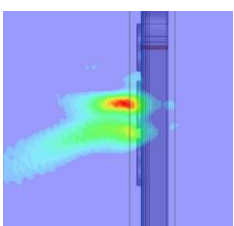
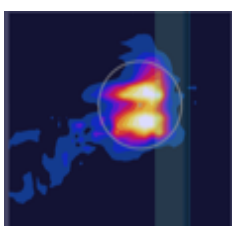
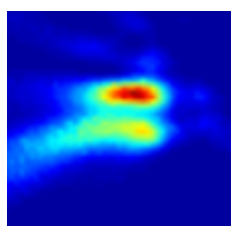
● Table 2-4, n261 ANT N-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|------------|---|---|--|---|
| 289 | S2 (Rear) |  |  |  |  |
| 286 | S4 (Right) |  |  |  |  |

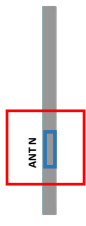
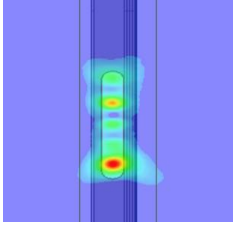
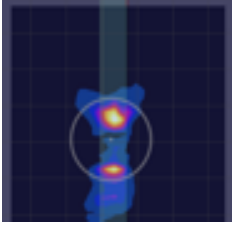
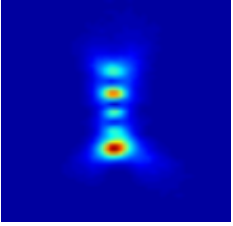
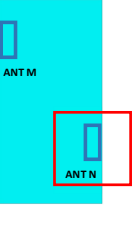
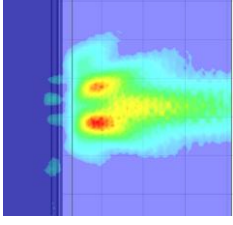
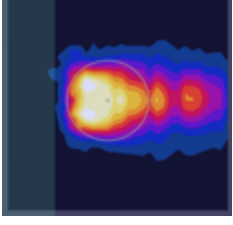
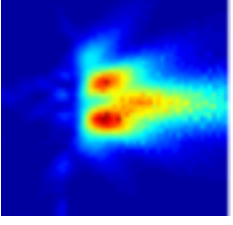
● Table 2-5, n260 ANT M-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|-----------|---|---|--|---|
| 28 | S2 (Rear) |  |  |  |  |
| | S3 (Left) |  |  |  |  |

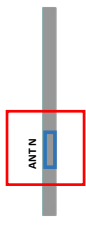
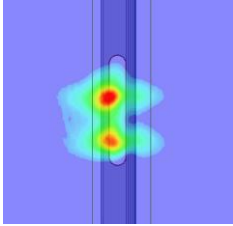
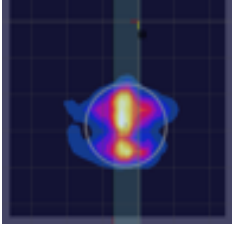
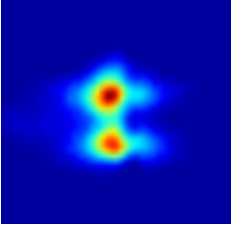
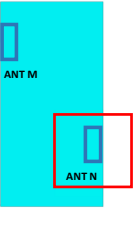
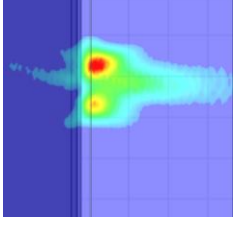
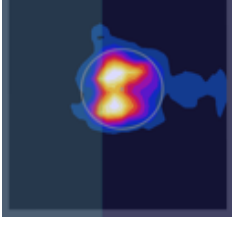
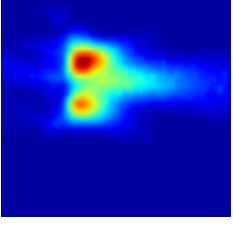
● Table 2-6, n260 ANT M-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|-----------|---|---|--|---|
| 291 | S2 (Rear) |  |  |  |  |
| 281 | S3 (Left) |  |  |  |  |

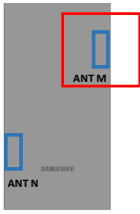
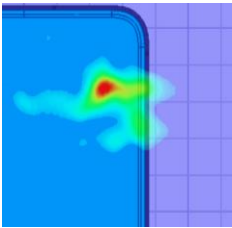
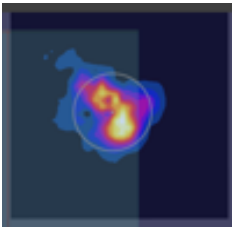
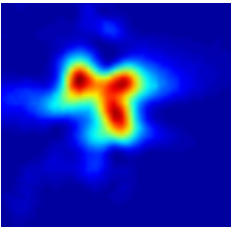
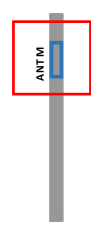
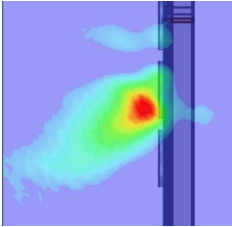
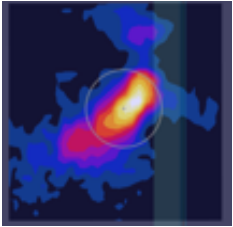
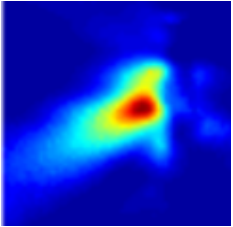
● Table 2-7, n260 ANT N-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|------------|---|---|--|---|
| 33 | S4 (Right) |  |  |  |  |
| | S1 (Front) |  |  |  |  |

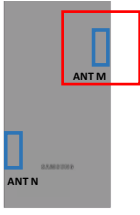
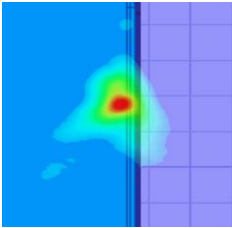
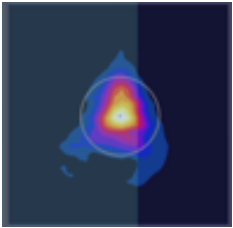
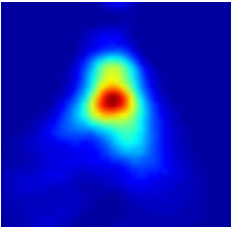
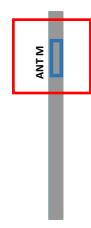
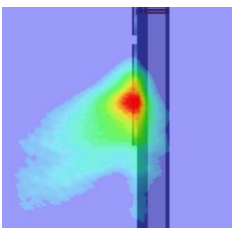
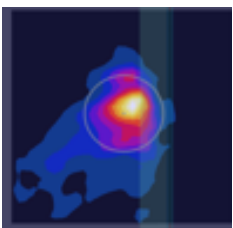
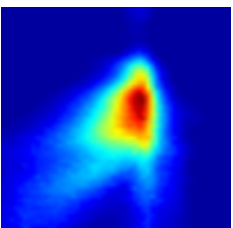
● Table 2-8, n260 ANT N-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|------------|---|---|--|---|
| 286 | S4 (Right) |  |  |  |  |
| | S1 (Front) |  |  |  |  |

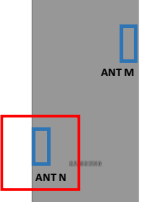
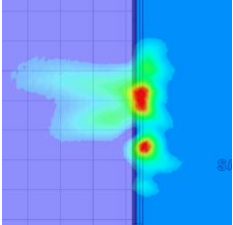
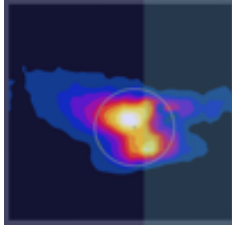
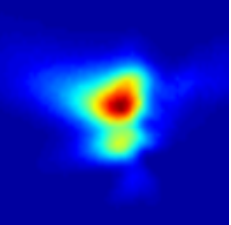
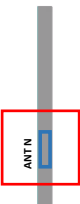
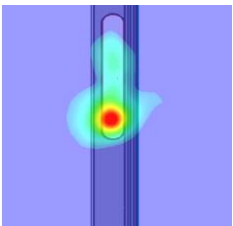
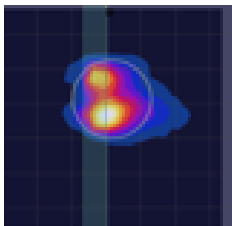
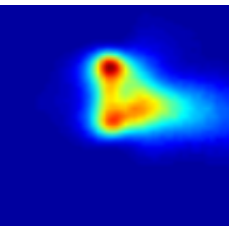
● Table 2-9, n258 ANT M-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|-----------|---|---|--|---|
| 35 | S2 (Rear) |  |  |  |  |
| | S3 (Left) |  |  |  |  |


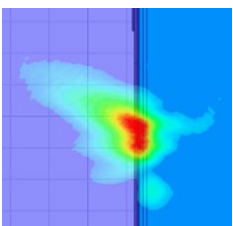
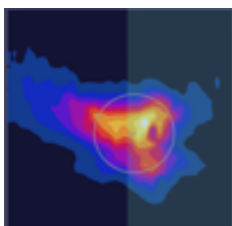
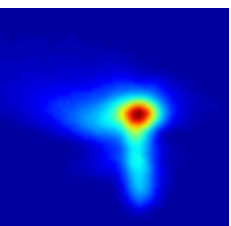
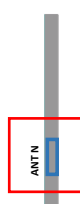
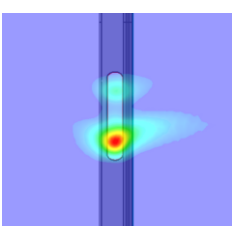
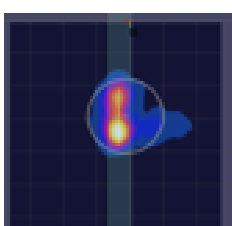
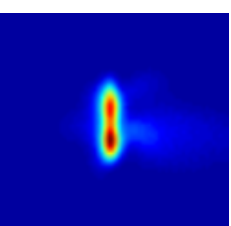
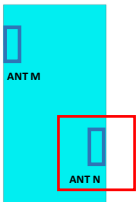
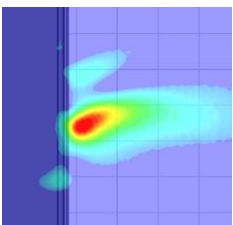
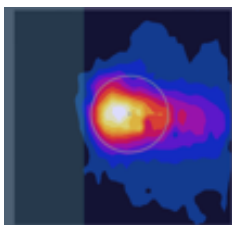
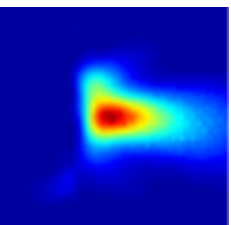
● Table 2-10, n258 ANT M-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|-----------|---|---|--|---|
| 284 | S2 (Rear) |  |  |  |  |
| | S3 (Left) |  |  |  |  |

● Table 2-11, n258 ANT N-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|------------|---|---|--|---|
| 40 | S2 (Rear) |  |  |  |  |
| 30 | S4 (Right) |  |  |  |  |

● Table 2-12, n258 ANT N-Patch

| Beam ID | Surface | View | Simulated PD | Measured PD | Print out from Qualcomm IPLG |
|---------|------------|---|---|--|---|
| 288 | S2 (Rear) |  |  |  |  |
| 286 | S4 (Right) |  |  |  |  |
| | S1 (Front) |  |  |  |  |

The Smart transmit GEN2 cannot be finalized until the additional verifications are performed and passed. Follow the below steps for verifications in the mid channel:

VERIFICATION 1: Use “Qualcomm Input Power Limit Generator” to print the PD plots for all the beams selected and evaluated for model validation.

- Throughout above comparisons (Table 2-1 to 2-12), the model validation including Input Power Limit Generator were verified.

